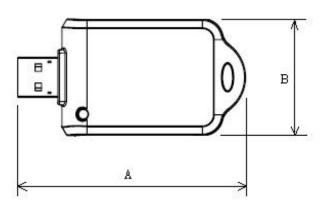
Description

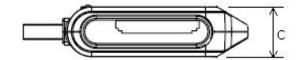
TS-RDS1 is a USB 2.0 Compact Card Reader. It is a small device specifically designed for fast, easy data transfer and exchange using multiple types of Memory Cards. The Card Reader accepts the direct insertion of; Secure Digital (SD™), Secure Digital High Capacity (SDHC™), miniSD™(SD™), miniSDHC™, MultiMediaCard (MMC™), MMCplus™, RS-MMC, and MMCmobile™ Memory Cards. In addition the Reader supports microSD™ and MMCmicro™ Memory Cards, when combined with their adapter.

Features

- Fully Compliant with the Hi-Speed USB 2.0 specification
- Hi-Speed Data transfer rates of up to 480Mb/s
- USB powered (no external power or battery needed)
- Supports many different types of Memory Cards without the need for an adapter :
 - Secure Digital Card (SD[™])
 - Secure Digital High Capacity (SDHC[™])
 - o miniSD[™]
 - o miniSDHC[™]
 - MultiMediaCard (MMC[™])
 - MMCplus[™]
 - o RS-MMC
 - o MMCmobile[™]
- Supports additional Memory Cards with an adapter :
 - o microSD[™]
 - o MMCmicro[™]
- LED indicates power connection

Placement



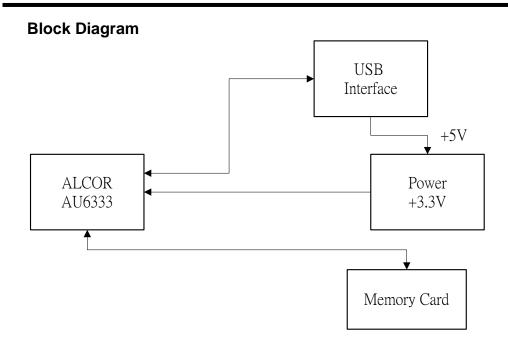


Dimensions

Side	Millimeters Inches	
Α	69.00 ± 1.00	2.72 ± 0.04
В	35.00 ± 1.00	1.38 ± 0.04
С	15.00 ± 1.00	0.59 ± 0.04

System Requirements

- Desktop or notebook computer with a working USB port
- One of the following Operating Systems:
 - o Windows® 2000
 - o Windows® Me
 - o Windows® XP
 - o Mac[™] OS 9.0. or later
 - Linux[™] Kernel 2.4.2, or later



Pinouts

Pin No.	Pin Name
01	VCC
02	USB-
03	USB+
04	VSS

Pin Identification

Symbol	Function
USB-	USB differential signal:
USB+	The pairs are used to transmit
	Data/Address/Command
VSS	Ground
VCC	USB Power Input

Absolute Maximum Rating

SYMBOL	PARAMETER	RATING	UNITS
V _{cc}	Power Supply	-0.3 to V _{CC} +0.3	V
V _{IN}	Input Voltage	-0.3 to 3.3	V
V _{out}	Output Voltage	-0.3 to V _{CC} +0.3	V
T _{STG}	Storage Temperature	-40 to 150	°C

Recommended Operating Conditions

SYMBOL	PARAMETER	MIN	ТҮР	мах	UNITS
V _{cc}	Power Supply	3.0	3.3	3.6	V
V _{IN}	Input Voltage	0	3.3	5.2	V
T _{OPR}	Operating Temperature	-40		115	°C

General DC Characteristics

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	мах	UNITS
I _{IN}	Input current	no pull-up or pull-down	-10	±1	10	μА
I _{oz}	Tri-state leakage current		-10	±1	10	μА
C _{IN}	Input capacitance	Pad Limit		2.8		ρF
Соит	Output capacitance	Pad Limit		2.8		ρF
C _{BID}	Bi-directional buffer capacitance	Pad Limit		2.8		ρF

DC Characteristics

SYMBOL	PARAMETER	CONDITIONS	Limits			UNIT
STMBOL	PARAMETER		MIN	TYP	MAX	ONTI
V _{CC}	Power supply	3.3V I/O	3.0	3.3	3.6	V
Vil	Input low voltage	LVTTL			0.8	V
V _{ih}	Input high voltage		2.0	-		V
V _{ol}	Output low voltage	I _{ol} =2~16mA			0.4	V
V_{oh}	Output high voltage	I _{oh} =2~16mA	2.4			V
R _{pu}	Input pull-up resistance	PU=high, PD=low	40	75	190	ΚΩ
R_{pd}	Input pull-down resistance	PU=low, PD=high	40	75	190	ΚΩ
I _{in}	Input leakage current	V _{in} = V _{CC} or 0	-10	±1	10	μΑ
I _{oz}	Tri-state output leakage current		-10	±1	10	μΑ

USB Transceiver Electrical Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
AVCC	Analog supply current		3.0	3.3	3.6	٧
VCC	Digital supply current		2.25	2.5	2.75	V
I _{CC}	Operating supply current	High speed operating at 480 MHz			73	mA
I _{CC(susp)}	Suspend supply current	In suspend mode, current with 1.5kΩ pull-up resistor on pin RPU disconnected			120	μА

Above technical information is based on industry standard data and tested to be reliable. However, Transcend makes no warranty, either expressed or implied, as to its accuracy and assumes no liability in connection with the use of this product. Transcend reserves the right to make changes in specifications at any time without prior notice.